

FMSW1102 DATA SHEET

SMA Reflective SPDT GaN High Power PIN Diode Switch from DC to 18 GHz Rated at 10 Watts 50ns Speed

The FMSW1102 is a high power Reflective SPDT PIN Diode Switch that operates from DC to 18 GHz. The module utilizes Gallium Nitride (GaN) and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband high power applications. The 50 ohm reflective design has impressive RF input power handling capability for cold switching up to +40 dBm, and incorporates TTL compatible driver circuitry for accurate logic control. Typical performance includes 1.3 dB insertion loss, 35 dB isolation, 1.6:1 VSWR, and 50 nsec switching speed. Operational temperature range is -45°C to +85°C and the bias voltage requirement is +5Vdc. The rugged and compact package supports SMA female connectors and is designed to meet a series of environmental conditions including Altitude, Vibration, Humidity, and Shock. Model FMSW1107 is the same switch design but includes an integrated heatsink.

Electrical Specifications

TTL Control Logic Off/Isolation: 0 to 0.8 V On/Low Loss: 2.8 to 5 V

Description	Min	Тур	Max	Units
Frequency Range	DC		18	GHz
Impedance		50		Ohms
VSWR		1.6:1	2:1	
Insertion Loss		1.3	2.3	dB
IL Temp. Coefficient		0.003		dB/degC
Isolation	23	35		dB
Switching Time		50	100	ns
P0.1dB		40		dBm
Input IP3		55		dBm
Input Power (CW)			10	Watts
DC Power Dissipation		0.5		
Watt				
Positive Operating Voltage		5		Vdc
Current @ 5 Vdc		100		mA
Operating Temperature	-45		+85	deg C

Performance by Frequency

Description	F1	F2	F3	F4	F5	Units
Frequency Range	DC to 6	6 to 12	12 to 18			GHz
VSWR, Max	1.3:1	1.8:1	2:1			
VSWR, Typ	1.15:1	1.6:1	1.6:1			
Insertion Loss, Ma	x 1.3	1.8	2.3			dB
Insertion Loss, Typ	o 0.8	1.3	1.7			dB
Isolation, Min	40	30	23			dB
Isolation, Typ	45	35	25			dB

Electrical Specification Notes:



Features:

- Reflective SPDT High Power PIN Diode Switch
- GaN Semiconductor Technology
- Reflective Design
- Frequency Range: DC to 18 GHz
- Insertion Loss: 1.3 dB typ
- Isolation: 35 dB typ
- VSWR: 1.6:1 typMaximum RF Input
- Maximum RF Input
 Power: +40 dBm
- Input IP3: 55 dBm typ
- Switching Speed: 50 nsec typ
- TTL Compatible Driver Circuitry
- 50 Ohm Design
- SMA Female Connectors
- Compact Package Design withstands up to 95% Relative Humidity
- -45°C to +85°C Operating Temperature

Applications:

- Aerospace & Defense
- Microwvae Radio
- Military & Commercial Communication
- VSAT
- SATCOM
- Test & Measuurement
- Wireless Infrastructure
- · Fiber Optics

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Note that below 100 Mhz the power handling capability is reduced by 6 dB and the noise figure will increase above IL Internal TTL Driver will become damaged if Negative Voltage is applied

*Cold Switching: Before changing any TTL signal(s), the RF input power must be blanked or the switch could become damaged

Absolute Maximum Rating

Parameter	Rating			
Biasing	+5V±10%			
TTL Control Voltage	0~0.8V/2.8~5V			



ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in approved ESD Workstation.

Mechanical Specifications

 Length
 1.57 in [39.88 mm]

 Width
 1.34 in [34.04 mm]

 Height
 0.37 in [9.4 mm]

 Weight
 0.21 lbs [95.25 g]

 Design
 Reflective, SPDT

 RF Connector
 SMA Female

Environmental Specifications

Temperature

Operating Range -45 to +85 deg C Storage Range -55 to +125 deg C

Humidity 100% RH @ 35°C, 95% RH @ 40°C

Shock 20G for 11ms Half Sinewave, 3 axis both directions Vibration 25g RMS (15° 2KHz) endurance, 1 hr per axis Altitude 30,000 ft. (Epoxy Sealed Controlled Environment)

Compliance Certifications (see product page for current document)

Plotted and Other Data

Notes:

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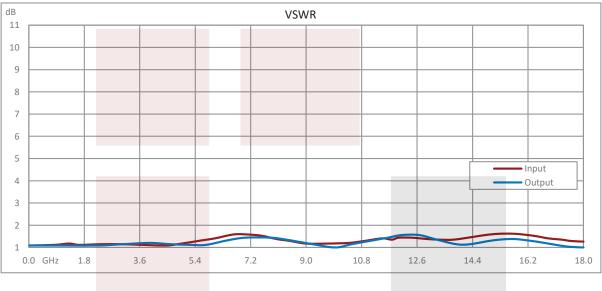
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Typical Performance Data











SMA Reflective SPDT GaN High Power PIN Diode Switch from DC to 18 GHz Rated at 10 Watts 50ns Speed from Fairview Microwave is in-stock and available to ship same-day. All of our RF/microwave products are available off-the-shelf from our ISO 9001:2008 certified facilities in Lewisville, Texas. Fairview Microwave is RF on-demand.

For additional information on this product, please click the following link: SMA Reflective SPDT GaN High Power PIN Diode Switch from DC to 18 GHz Rated at 10 Watts 50ns Speed FMSW1102

URL: https://www.fairviewmicrowave.com/sma-spdt-pin-diode-switch-18-ghz-10-watts-fmsw1102-p.aspx

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